onsemi

Diode – Small Signal

MMBD1501A, MMBD1503A, MMBD1504A, MMBD1505A

ABSOLUTE MAXIMUM RATINGS

(Values are at $T_A = 25^{\circ}C$ unless otherwise noted.) (Notes 1, 2)

| Symbol | Parameter | | Value | Unit |
|--------------------|------------------------------------|---------------------------|-------------|------|
| V _{RRM} | Maximum Repetitive Reverse Voltage | | 200 | V |
| I _{F(AV)} | Average Rectified Forward Current | | 200 | mA |
| I _{FSM} | Non-Repetitive Peak Forward | Pulse Width = 1.0 s | 1.0 | А |
| | Surge Current | Pulse Width = 1.0 μ s | 2.0 | |
| T _{STG} | Storage Temperature Range | | –55 to +150 | °C |
| TJ | Operating Junction Temperature | | –55 to +150 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. These ratings are based on a maximum junction temperature of 150°C.

2. These are steady-state limits. **onsemi** should be consulted on applications involving pulsed or low-duty-cycle operations.

THERMAL CHARACTERISTICS

(Values are at $T_A = 25^{\circ}C$ unless otherwise noted.)

| Symbol | Parameter | Value | Unit |
|-----------------------|--|-------|------|
| PD | Power Dissipation | 350 | mW |
| $R_{	extsf{	heta}JA}$ | Thermal Resistance, Junction-to-Ambient | 357 | °C/W |

ELECTRICAL CHARACTERISTICS

(Values are at $T_A = 25^{\circ}C$ unless otherwise noted.)

| Symbol | Parameter | Conditions | Min | Max | Unit |
|----------------|----------------------|---|------|------|------|
| V _R | Breakdown Voltage | I _R = 5.0 μA | 200 | - | V |
| VF | Forward Voltage | I _F = 1.0 mA | 620 | 720 | mV |
| | | I _F = 10 mA | 720 | 830 | mV |
| | | I _F = 50 mA | 800 | 890 | mV |
| | | I _F = 100 mA | 830 | 930 | mV |
| | | I _F = 200 mA | 0.87 | 1.10 | V |
| | | I _F = 300 mA | 0.90 | 1.15 | V |
| I _R | Reverse Current | V _R = 125 V | - | 1.0 | nA |
| | | V _R = 125 V, T _A = 150°C | - | 3.0 | μA |
| | | V _R = 180 V | - | 10.0 | nA |
| | | V _R = 180 V, T _A = 150°C | - | 5.0 | μΑ |
| C _T | Total Capacitance | V _R = 0, f = 1.0 MHz | - | 4.0 | pF |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



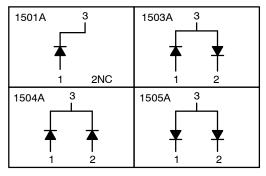


SOT-23

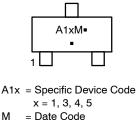
SOT-23 (TO-236) CASE 318-08

CASE 318BM

CONNECTION DIAGRAMS



MARKING DIAGRAM

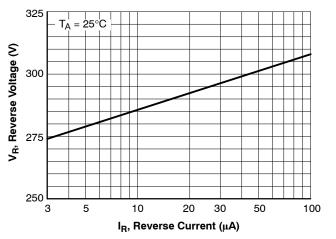


= Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information on page 3 of this data sheet.

MMBD1501A, MMBD1503A, MMBD1504A, MMBD1505A



TYPICAL CHARACTERISTICS

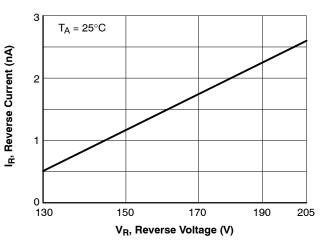
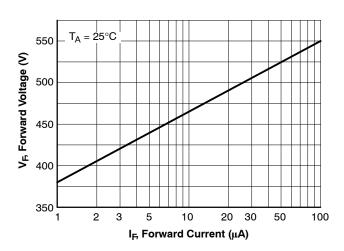
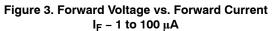
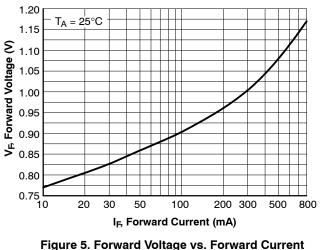


Figure 1. Reverse Voltage vs. Reverse Current I_R – 3.0 to 100 μA







gure 5. Forward Voltage vs. Forward Curren I_F – 10 to 800 mA

Figure 2. Reverse Current vs. Reverse Voltage V_R – 130 to 205 V $\,$

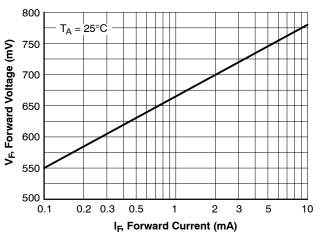
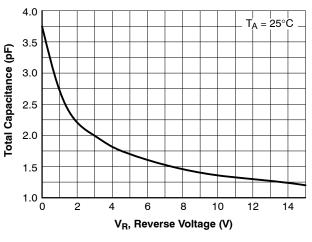
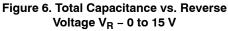


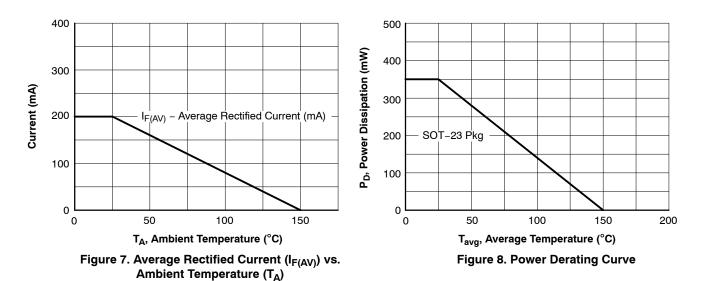
Figure 4. Forward Voltage vs. Forward Current I_F – 0.1 to 10 mA





MMBD1501A, MMBD1503A, MMBD1504A, MMBD1505A

TYPICAL CHARACTERISTICS (Continued)



ORDERING INFORMATION

| Part Number | Specific Device Marking | Package Type | Shipping [†] | |
|----------------|-------------------------|---------------------|----------------------------|--|
| MMBD1501A | A11 | SOT-23 (TO-236) | 3,000 / Tape & Reel (7") | |
| MMBD1503A | A13 | (Pb-Free) | | |
| MMBD1503A_D87Z | A13 | SOT-23 (Pb-Free) | 10,000 / Tape & Reel (13") | |
| MMBD1504A | A14 | SOT-23 (TO-236) | 3,000 / Tape & Reel (7″) | |
| MMBD1505A | A15 | (Pb-Free) | | |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.





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SOT-23 CASE 318BM **ISSUE A** DATE 01 SEP 2021 NOTES: UNLESS OTHERWISE SPECIFIED А D A) REFERENCE JEDEC REGISTRATION 3 TO-236, VARIATION AB, ISSUE H. В B) ALL DIMENSIONS ARE IN MILLIMETERS. C) DIMENSIONS ARE INCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR EXTRUSIONS. D) DIMENSIONING AND TOLERANCING PER E1 ASME Y14.5M - 2009. MILLIMETERS DIM SEE DETAIL A NOM. MIN. MAX. А 1.20 2 A1 0.00 0.05 0.10 (z) A2 0.93 REF b b 0.37 0 44 0.60 е ⊕ 0.20(M) A B 0.08 0.23 с 0.15 e1 D 2.72 2.92 3.12 F Е 2.10 2.40 2.70 E1 1.15 1.30 1.50 0.95 е 0.95 BSC (A2) A1 1.90 BSC e1 0.20 L --------0.10M C \square 1.40 L1 0.55 REF С z 0.29 REF GAGE PLANE 2.20 0.25 С 1 SEATING - 1.00 PLANE - (L1) -1.90 DETAIL A LAND PATTERN SCALE: 2X RECOMMENDATION *FOR ADDITIONAL INFORMATION ON OUR PB-FREE STRATEGY AND SOLDERING GENERIC DETAILS, PLEASE DOWNLOAD THE ON **MARKING DIAGRAM*** SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D. XXXM-. *This information is generic. Please refer to device data sheet for actual part marking. XXX = Specific Device Code Pb-Free indicator, "G" or microdot "•", may Μ = Date Code or may not be present. Some products may = Pb-Free Package not follow the Generic Marking. Electronic versions are uncontrolled except when accessed directly from the Document Repository. **DOCUMENT NUMBER:** 98AON13784G Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. **DESCRIPTION:** SOT-23 PAGE 1 OF 1

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